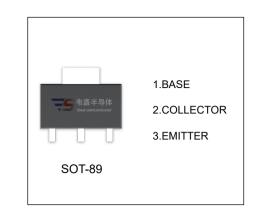


2SA1204 TRANSISTOR (PNP)

FEATURES

- Complementary to 2SC2884
- Small Flat Package
- Audio Frequency Amplifier Application
- High DC Current Gain

MAXIMUM RATINGS (T_a=25℃ unless otherwise noted)



Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	-35	V
V _{CEO}	Collector-Emitter Voltage	-30	V
V _{EBO}	Emitter-Base Voltage	-5	V
Ic	Collector Current	-0.8	Α
Pc	Collector Power Dissipation	500	mW
R _{θJA}	Thermal Resistance From Junction To Ambient	250	°C/W
T _J ,T _{stg}	Operation Junction and Storage Temperature Range	-55~+150	$^{\circ}$

ELECTRICAL CHARACTERISTICS (T_a=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C = -0.1mA,I _E =0	-35			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C =-10mA,I _B =0	-30			V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E =-0.1mA,I _C =0	-5			V
Collector cut-off current	I _{CBO}	V _{CB} =-35V,I _E =0			-100	nA
Emitter cut-off current	I _{EBO}	V _{EB} =-5V,I _C =0			-100	nA
DC current gain	h _{FE(1)}	V _{CE} =-1V, I _C =-100mA	100		320	
De current gant	h _{FE(2)}	V _{CE} =-1V, I _C =-700mA	35			
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =-500mA,I _B =-20mA			-0.7	V
Base-emitter voltage	V_{BE}	V _{CE} =-1V, I _C =-10mA	-0.5		-0.8	V
Collector output capacitance	C _{ob}	V _{CB} =-10V,I _E =0, f=1MHz		19		pF
Transition frequency	f _T	Vce=-5V,Ic= -10mA		120		MHz

CLASSIFICATION OF $h_{\text{FE}(1)}$

RANK	0	Υ	
RANGE	100 - 200	160 - 320	
MARKING	RO	RY	